

## Carbon Sputtering Technology for MPGD detectors

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Carbon sputtering is a promising technology for making resistive electrodes for MPGDs (Micro Pattern Gaseous Detectors). The research on this technology started in the context of the development of MicroMEGAS detectors for the ATLAS muon system upgrade. By sputtering carbon layers of varying thickness (a few hundred to a few thousand angstrom) and doping the nitrogen, the surface resistivity can be controlled between 50 k $\Omega$ /sq. and 4 G $\Omega$ /sq. Several small (10  $\times$  10 cm<sup>2</sup>) and medium size foils (50  $\times$  100 cm<sup>2</sup>) have been produced and successfully tested. The carbon layer is deposited on thin (25 to 50  $\mu$ m) insulating foils (e.g., Kapton) by sputtering resulting in a good uniformity (<30%) of the resistivity. Extremely fine electrodes structures (<50  $\mu$ m) can be achieved using the liftoff process technique. The foils produced so far are extremely robust with respect to mechanical and chemical damage. We report on the fabrication technique and the performance in operating detectors. Given the positive experience with MicroMEGAS detectors we also address other possible applications that could be interesting for MPGD detectors, e.g., Micro Pixel Chambers, GEMs, etc.

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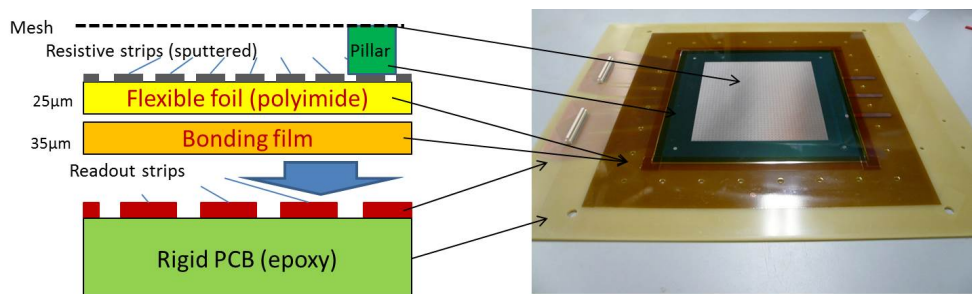
## 1. Introduction

The MPGD (MicroMEGAS, GEM,  $\mu$ -PIC, etc.) are very promising particle detectors which provides both fine granularity and wide detection area. The electric discharge problem has been very critical problem in MPGDs, however it was almost overcome for using high resistive electrodes [1, 2, 3]. As for the resistive material, generally the surface resistivity of around  $100\text{k}\Omega/\text{sq}$ . –  $1\text{G}\Omega/\text{sq}$ . are required. We are proposing a novel method for making a resistive pattern for MPGDs, using the carbon sputtering with lift off process, instead of the standard carbon black loaded material. The large foil, more than a few  $\text{m}^2$ , can be made in industrial sputtering process. It meets the requirements for HEP experiments, which need large size detectors. This paper discusses briefly the carbon sputtering foil development for mainly ATLAS MicroMEGAS for LHC upgrade [4]. The prototype production of small test chamber and large ( $\sim 1\text{m}$ ) MicroMEGAS foils, and resistivity control are described. Details of those results and other studies for resistive foils will be presented in a forthcoming paper.

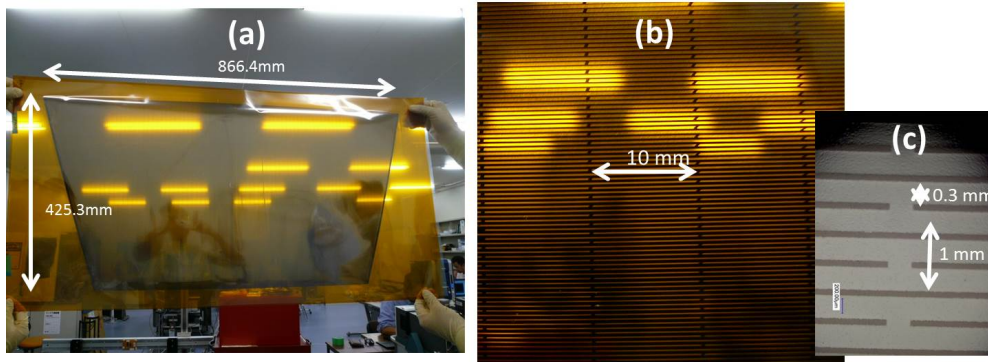
## 2. Sputtering and liftoff technique

The sputtering technology is now commonly used for producing thin metal or non-metal foils. We have used a large industrial sputtering chamber in Be-Sputter Co., Ltd. Using a rotating drum, the  $4.5\text{m} \times 1\text{m}$  foil can be used as a substrate. The carbon is sputtered on the substrate as an amorphous diamond like carbon (a-DLC) using graphite sputtering target. To make the structure of the MPGD electrodes, the liftoff process is combined. Firstly, the negative pattern of the electrodes image is formed by photo resist, as the usual PCB (printed circuit board) production technique. Next, the carbon is sputtered on the surface, and then, the resists are removed chemically. The liftoff is processed by the PCB industrial company, Raytech Inc. The precisions of the sputtering pattern is determined by photo resist imaging. A few tens micrometer accuracy is possible for that precision using the commonly used industrial PCB process.

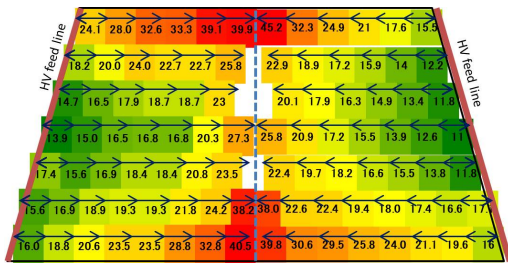
Prototypes of MicroMEGAS with resistive strips were produced and tested. The small prototype with  $10\text{cm} \times 10\text{cm}$  detection area has been made, as shown in figure 1. Gas gain above 10000 was observed using  $\text{Ar}(85\%) + \text{CO}_2(15\%)$  mixed gas. Operations in fast neutron condition ( $\sim 2$



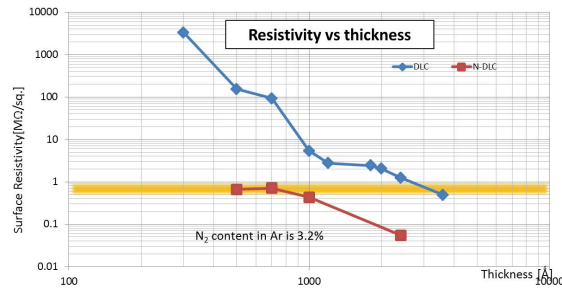
**Figure 1:** Schematic cross section of the  $10\text{ cm} \times 10\text{ cm}$  resistive MicroMEGAS with sputtered carbon, and the picture of a prototype chamber.



**Figure 2:** Schematic cross section of the 10 cm×10 cm resistive MicroMEGAS with sputtered carbon, and the picture of a prototype chamber.



**Figure 3:** Resistivity map for large size resistive strip foil. The resistivity from HV feed line (both inclined side) were measured for each 5 cm point. Values are in MΩ. The predicted resistive value is not calculated yet, but this result agree well with approximate estimates, and the uniformity is roughly estimated to be below 30 % [6].



**Figure 4:** Surface resistivity as a function of the sputtered carbon thickness. The blue line shows the resistivity of pure carbon sputtering, and the red line shows that of Nitrogen doped foils. The orange band represents the required resistivity for the ATLAS MicroMEGAS.

MeV neutron,  $10^6$  n/sec/cm<sup>2</sup>) were also tested, and stable operation and spark reduction were confirmed. No damage was observed after the detector operation of more than  $10^{10}$  neutron/cm<sup>2</sup>[5]. Large size foils for the ATLAS MicroMEGAS prototype were also produced. Figure 2 shows a pictures of the large foil (a), a magnified picture (b) and a microscopic picture (c). The trapezoidal shape of 85 cm × 45 cm with 415 μm pitch strips were produced successfully. The uniformity of the resistivity was measured for this large foil. Figure 3 shows the measured resistivity from the inclined side, which is designed as high voltage provider. The results agree well with the calculated values within 30 % . Total 8 foils were produced for ATLAS MicroMEGAS prototype chamber [7], and being tested.

### 3. Resistivity control

The resistivity of the carbon sputtered foil is dependent on the carbon thickness. The surface resistivity for carbon thickness of 30 nm is about 4G Ω/sq., and the thickness of 360 nm is

500 k $\Omega$ /sq. Figure 4 shows the surface resistivity dependence on the carbon thickness from our measurement. ATLAS MicroMEGAS require the surface resistivity of around 700k  $\Omega$ /sq., and carbon thickness of 300 nm-360 nm was required. In other hands, the deposition speed of carbon is very slow. In the case of our production, the maximum deposition speed using single target is 30 nm/hour. The deposition time for producing the prototype foils in figure 2(a) was 6 hours, which is too long for mass production.

We have developed a new method for reducing the surface resistivity with shorter deposition time. To reduce the surface resistivity with shorter deposition time, we have conceived to dope the nitrogen into the carbon foil. This idea originates from the analogy with n-doped semiconductors. Generally, the molecular structure of the sputtered carbon is a-DLC, which is characterized by a low amount of charge carriers. Nitrogen doping is to increase carrier electrons. We have mixed the nitrogen gas into the Argon gas while sputtering process. In our experience, where carbon was sputtered with nitrogen gas of 3.2 %, we got resistive foil of 400 k $\Omega$ /sq. with 100 nm thickness. This resistivity is ten times smaller than pure carbon sputtering case. The measured resistivity with 3.2 % nitrogen gas mixing is shown in figure 4. From those results, we can get the appropriate surface resistivity for ATLAS MicroMEGAS with only 70 nm thickness, with which the deposition time is about 40 minutes using double station of carbon targets.

#### 4. Summary

The carbon sputter and liftoff method is newly developed for producing MPGD resistive electrodes. Our tests show very promising results, and many other measurements e.g. mechanical tolerance tests, chemical tests, high voltage breakdown tests and detailed results of above tests will be detailed in a forthcoming publication.

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- [5] Details will be shown in forthcoming paper in preparation.
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